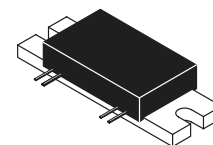


The RF Line  
**PCS Band**  
**RF Power LDMOS Amplifiers**

**MHW1810-1**  
**MHW1810-2**

**1805–1880 MHz, 10 W**  
**RF POWER LDMOS AMPLIFIERS**

- Specified 26 Volts, 1805–1880 MHz, Class AB Characteristics  
Output Power = 16 Watts CW Typ  
Power Gain = 26 dB Typ @ 10 Watts (MHW1810-1)  
Power Gain = 34 dB Typ @ 10 Watts (MHW1810-2)  
Efficiency = 34% Min @ 10 Watts
- 50 Ω Input/Output System
- Designed for GSM Linearity Requirements



CASE 301AW-02, STYLE 1

**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
DC Supply Voltage	$V_S$	28	Vdc
DC Bias Voltage	$V_{bias}$	28	Vdc
RF Input Power	$P_{in}$	MHW1810-1: 21 MHW1810-2: 16	dBm
RF Output Power	$P_{out}$	20	W
Operating Case Temperature Range	$T_C$	-10 to +90	°C
Storage Temperature Range	$T_{stg}$	-30 to +100	°C

**ELECTRICAL CHARACTERISTICS** ( $T_C = +25^\circ\text{C}$ ,  $V_S = 26\text{ Vdc}$ ;  $V_{bias} = 5\text{ Vdc}$ ; 50 Ω system, unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	1805	—	1880	MHz
Quiescent Current ( $P_{in} = 0\text{ mW}$ )	$I_{DQ}$	100	—	150	mA
Bias Current	$I_{bias}$	—	—	2	mA
Output Power at 1 dB Compression	$P_{1dB}$	10	14	—	W
Power Gain ( $P_{out} = 10\text{ W}$ ) ( $P_{out} = 10\text{ W}$ )	$G_p$	MHW1810-1: 24 MHW1810-2: 32	26 34	28 36	dB
Efficiency ( $P_{out} = 10\text{ W}$ )	$\eta$	34	—	—	%
Input VSWR ( $P_{out} = 10\text{ W}$ )	VSWR <sub>in</sub>	—	—	1.8:1	—
Harmonics at $2f_o$ ( $P_{out} = 10\text{ W}$ )	$H_2$	—	—	-35	dBc
Harmonics at $3f_o$ ( $P_{out} = 10\text{ W}$ )	$H_3$	—	—	-45	dBc
Reverse IMD; $P_{out} = 10\text{ W}$ ; Preverse = -40 dBc ( $F1 = F0 \pm 200\text{ kHz}$ @ -40 dBc)	IMD <sub>r</sub>	—	—	-50	dBc
Load Mismatch Stress Load VSWR = 5:1, All Phase Angles	$\psi$	No Degradation in Output Power			
Stability ( $P_{out} = 10\text{ mW}$ to $10\text{ W}$ , $V_S \leq 26\text{ Vdc}$ ) Load VSWR = 5:1, All Phase Angles	—	All Spurious Outputs More Than 60 dB Below Desired Signal			

NOTE – **CAUTION** – MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.

**EXTREME CASE ELECTRICAL CHARACTERISTICS** ( $T_C = -10$  to  $+85^\circ\text{C}$ ,  $V_S = 23.5$  to  $26$  Vdc,  $V_{\text{bias}} = 3$  to  $26$  Vdc,  $50\ \Omega$  system, unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Frequency Range	BW	1805	—	1880	MHz
Quiescent Current ( $P_{\text{in}} = 0$ mW)	$I_{\text{DQ}}$	100	—	160	mA
Bias Current	$I_{\text{bias}}$	—	—	2	mA
Output Power at 1 dB Compression	$P_{1\text{dB}}$	8	—	—	W
Power Gain Variation for a Given Part ( $P_{\text{out}} = 10$ W)	$G_p$	—	5	6.5	dB
Efficiency ( $P_{\text{out}} = 10$ W)	$\eta$	32	—	—	%
Input VSWR	$\text{VSWR}_{\text{in}}$	—	—	2:1	—
Harmonics at $2f_o$	$H_2$	—	—	-35	dBc
Harmonics at $3f_o$	$H_3$	—	—	-45	dBc
Reverse IMD; $P_{\text{out}} = 10$ W; Preverse = -40 dBc ( $F1 = F0 \pm 200$ kHz @ -40 dBc)	$\text{IMD}_r$	—	—	-50	dBc
Load Mismatch Stress Load VSWR = 5:1, All Phase Angles	$\psi$	No Degradation in Output Power			
Stability ( $P_{\text{out}} = 10$ mW to 10 W, $V_S \leq 26$ Vdc) Load VSWR = 5:1, All Phase Angles	—	All Spurious Outputs More Than 60 dB Below Desired Signal			

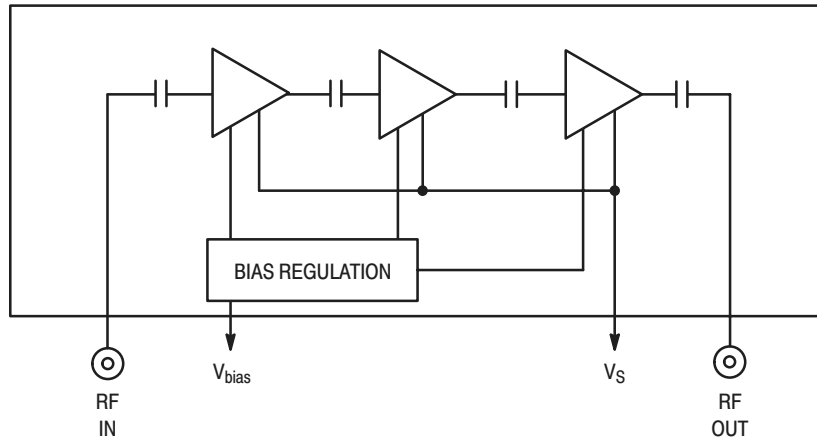


Figure 1. Internal Diagram

TYPICAL CHARACTERISTICS  
MHW1810-1

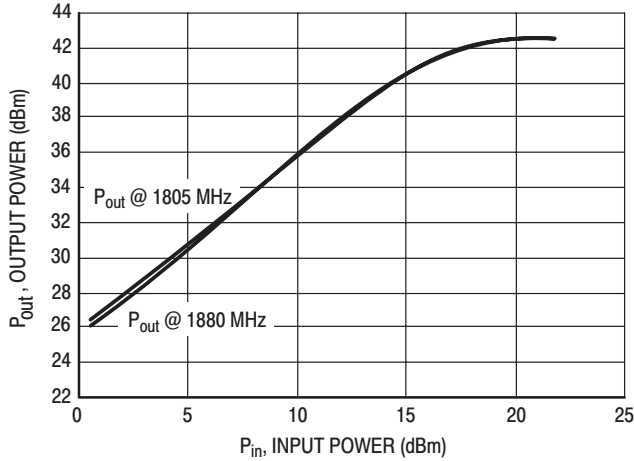


Figure 2. Output Power versus Input Power

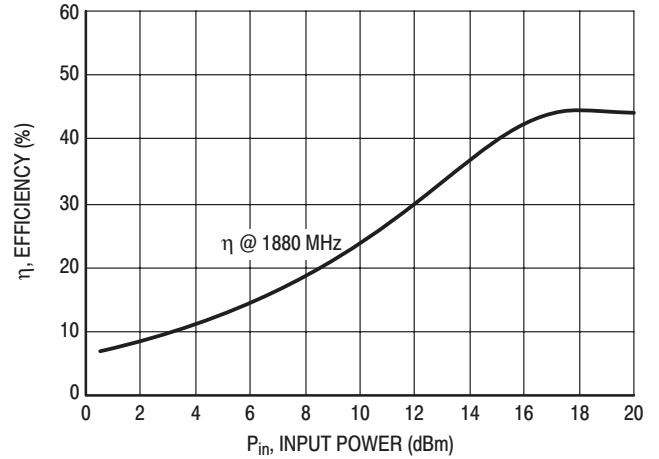


Figure 3. Efficiency versus Input Power

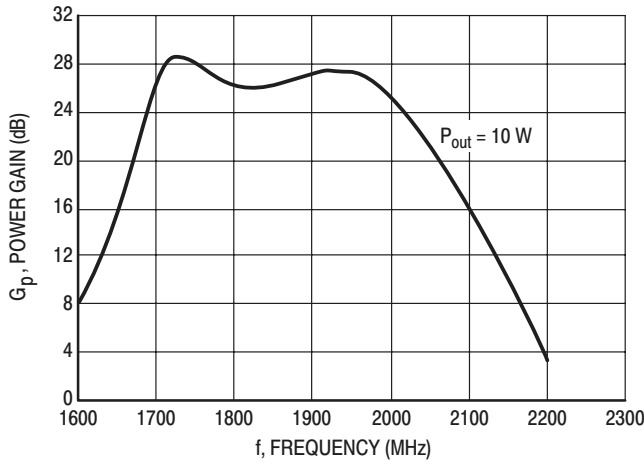


Figure 4. Power Gain versus Frequency

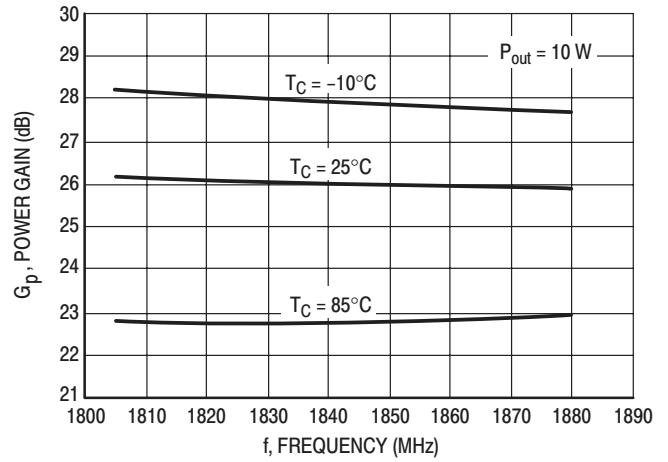


Figure 5. Gain versus Frequency

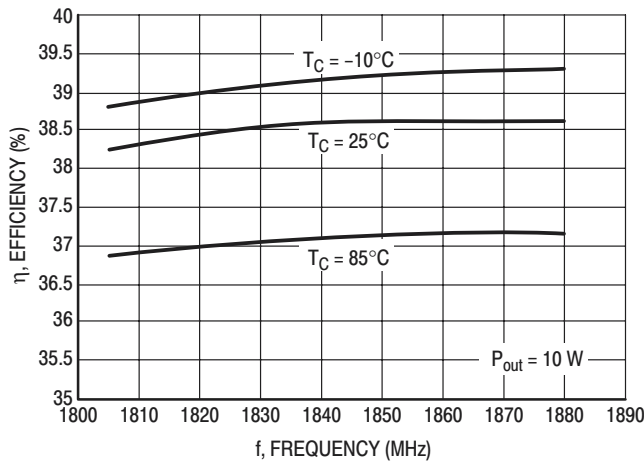


Figure 6. Efficiency versus Frequency

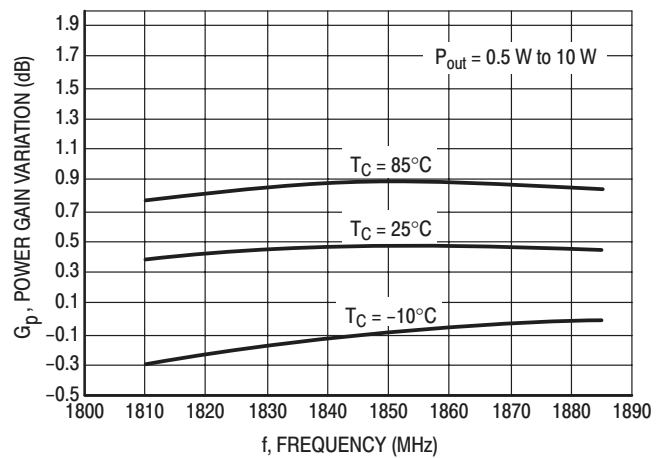


Figure 7. Power Gain Variation versus Frequency

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TYPICAL CHARACTERISTICS  
MHW1810-1

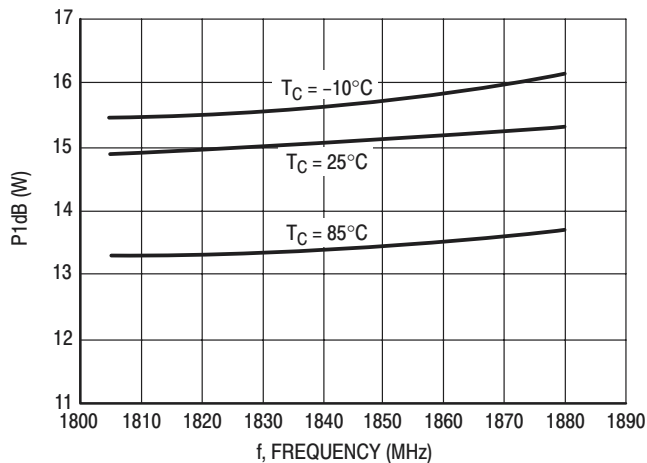


Figure 8. P1dB versus Frequency

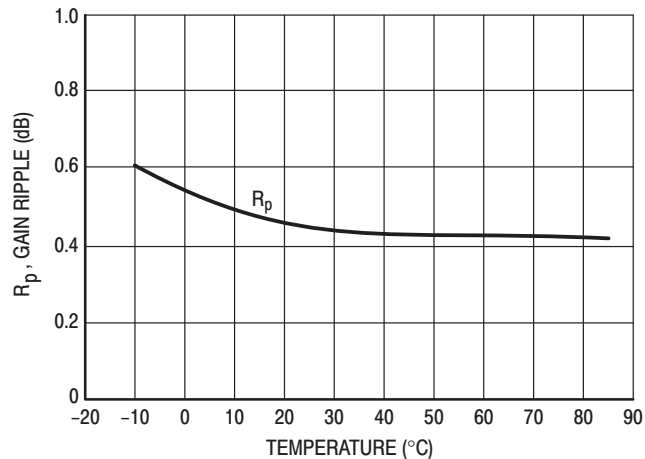


Figure 9. Gain Ripple versus Temperature

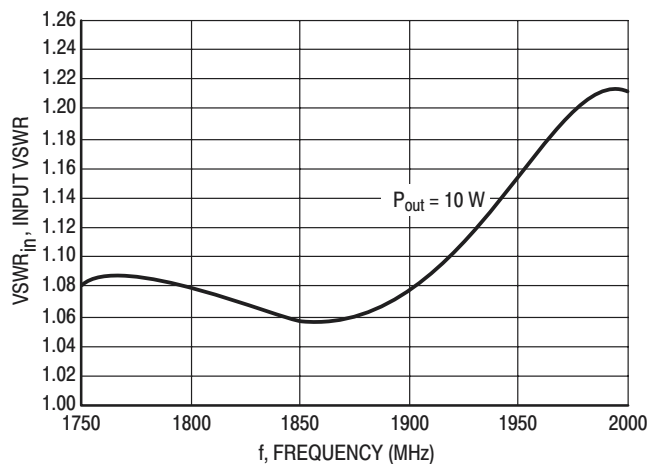


Figure 10. Input VSWR

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TYPICAL CHARACTERISTICS  
MHW1810-2

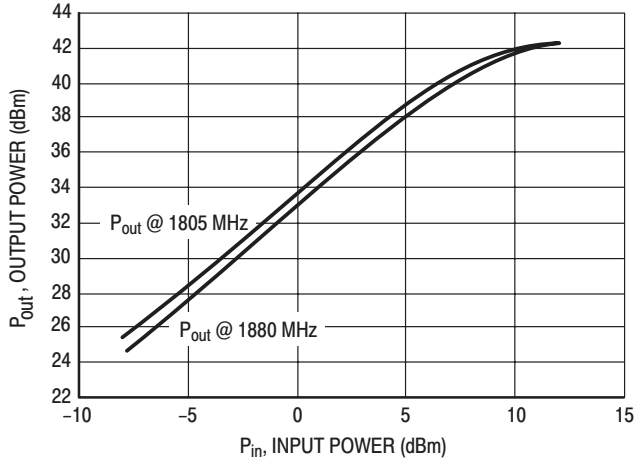


Figure 11. Output Power versus Input Power

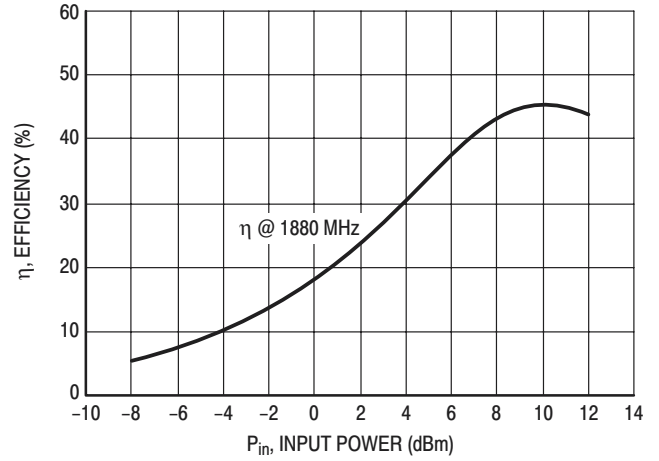


Figure 12. Efficiency versus Input Power

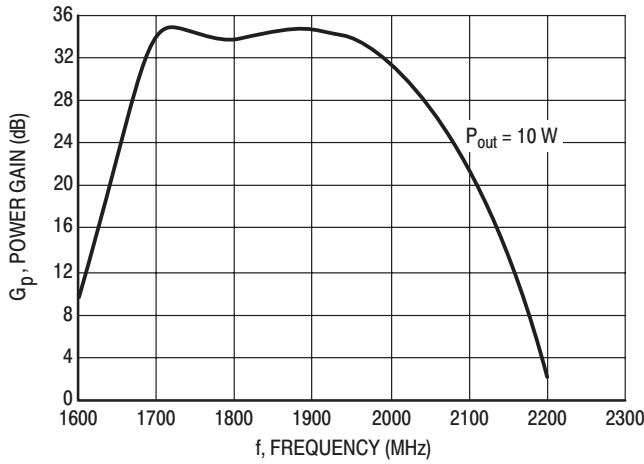


Figure 13. Power Gain versus Frequency

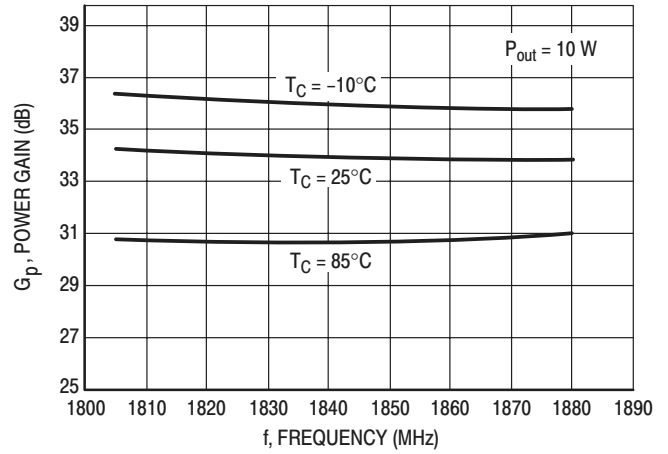


Figure 14. Gain versus Frequency

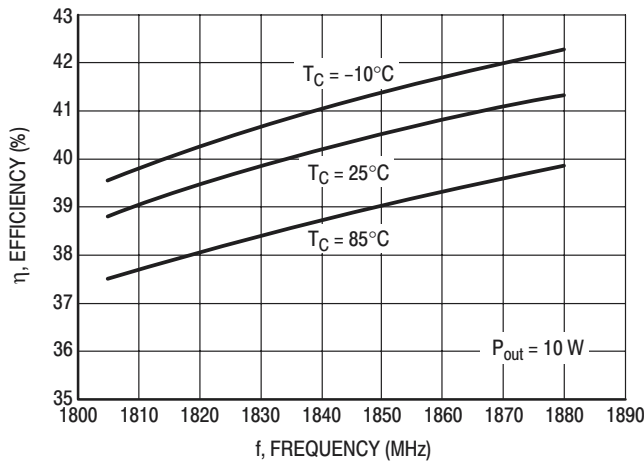


Figure 15. Efficiency versus Frequency

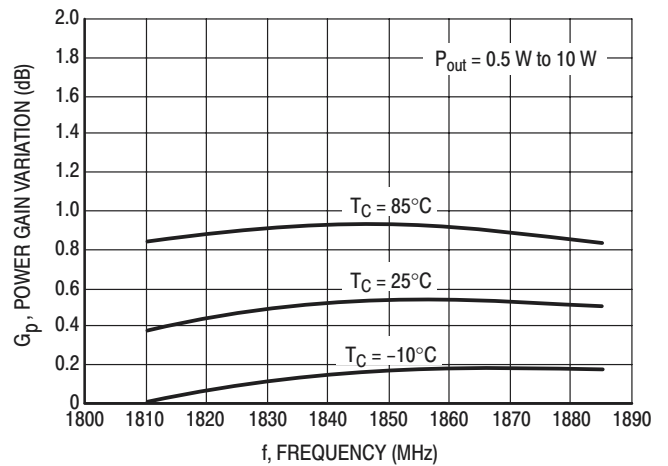


Figure 16. Power Gain Variation versus Frequency

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TYPICAL CHARACTERISTICS  
MHW1810-2

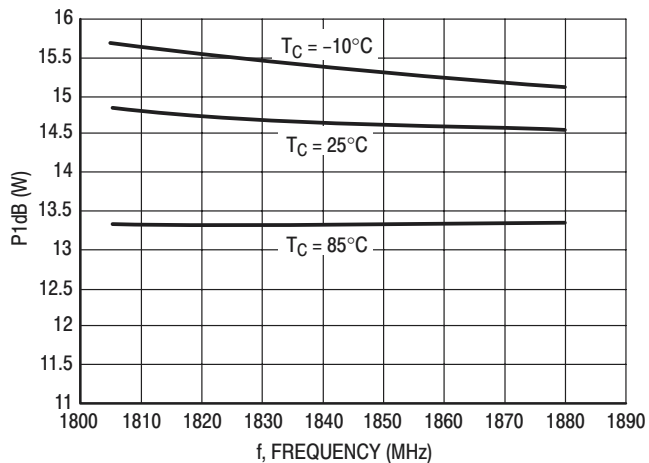


Figure 17. P1dB versus Frequency

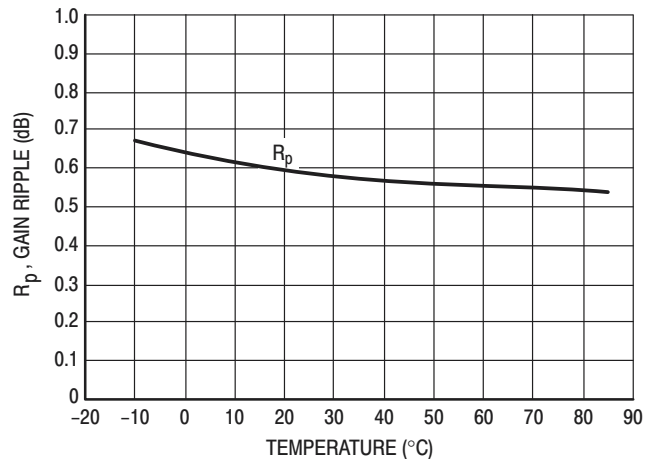


Figure 18. Gain Ripple versus Temperature

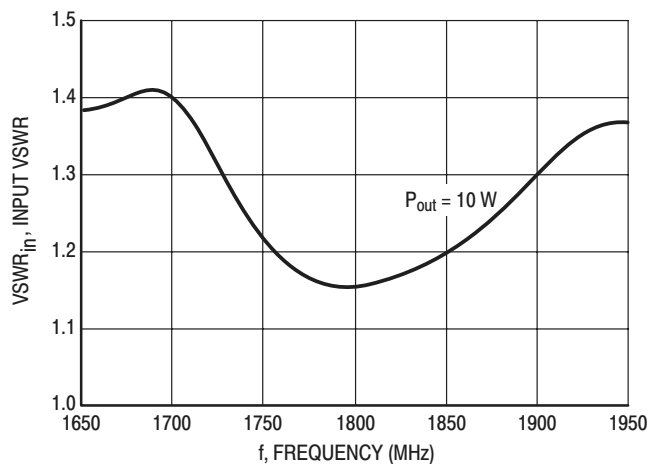


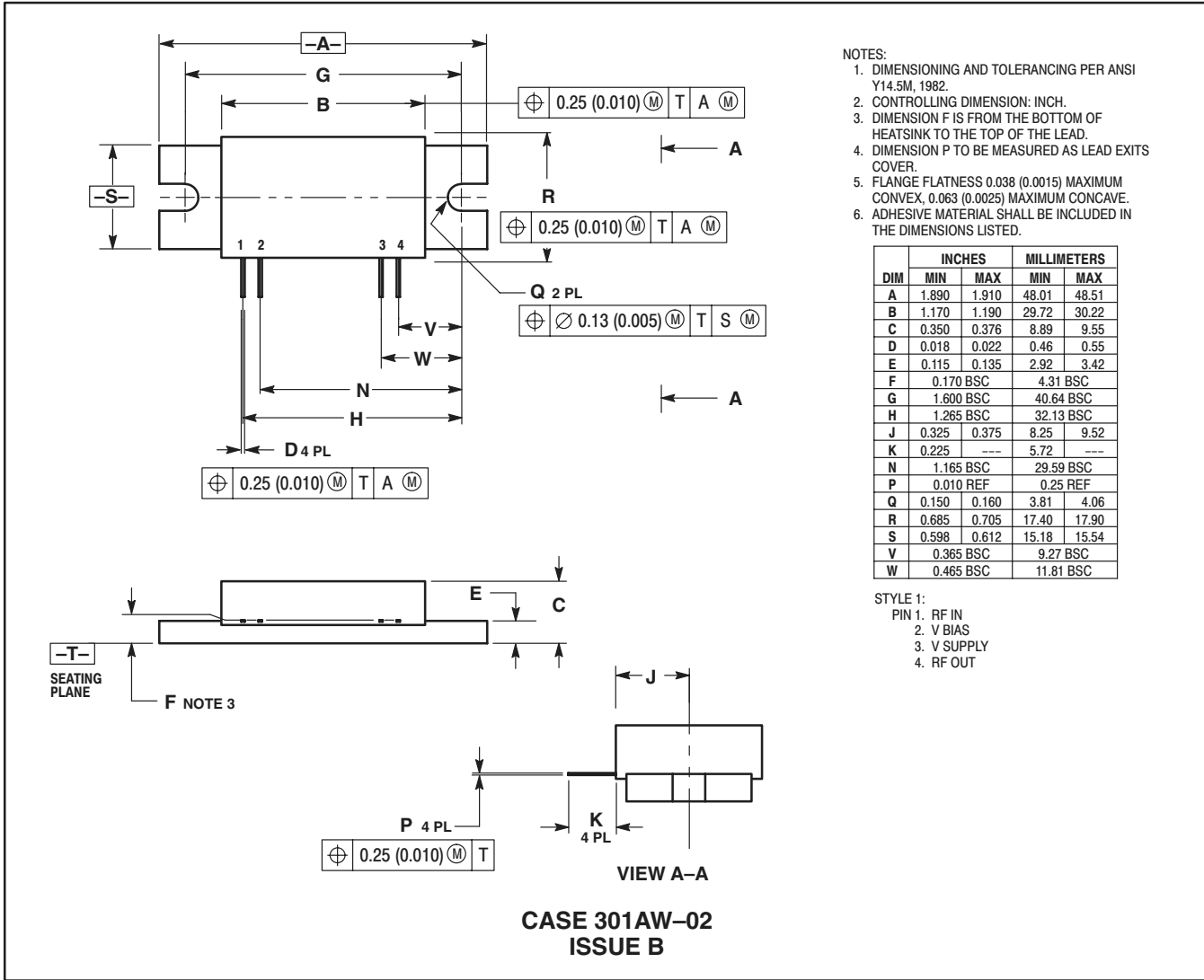
Figure 19. Input VSWR

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# NOTES

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